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6.012 Microelectronic Devices and Circuits

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Lecture 1 – 6.012 overview

February 6, 2001

- Contents:
 - Overview of 6.012

- Reading Assignment:
 - Howe and Sodini, Ch. 1

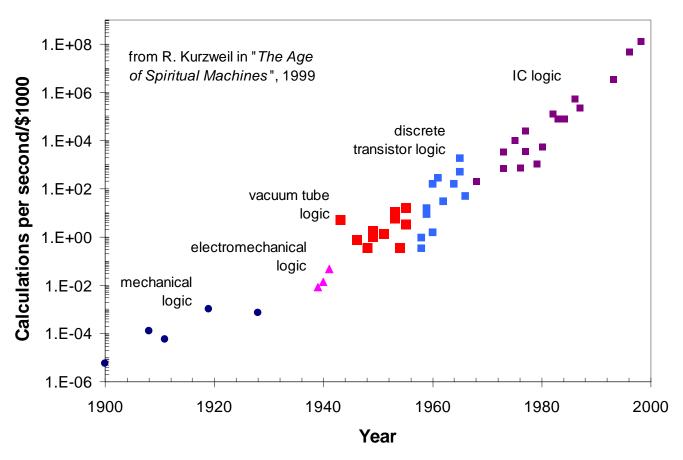




Overview of 6.012

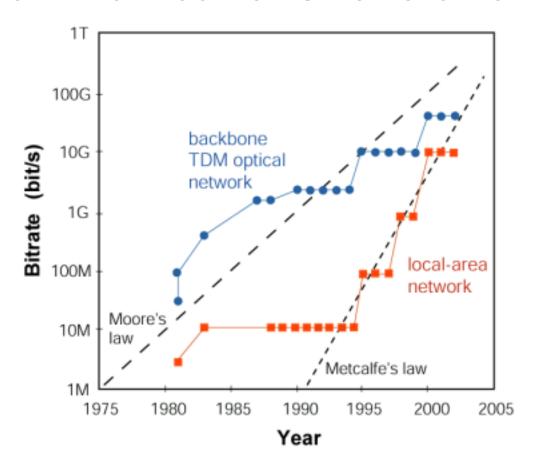
- Introductory subject to microelectronic devices and circuits
- Microelectronics is cornerstone of:
 - Computer revolution
 - Communications revolution

Microelectronics: cornerstone of computing revolution



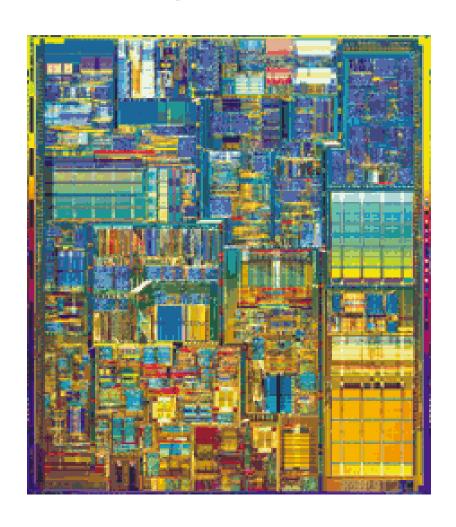
In last 30 years, computer performance per dollar has improved more than a million fold!

Microelectronics: cornerstone of communications revolution



In last 20 years, communication bandwidth through a single optical fiber has increased by ten-thousand fold.

Si digital microelectronics today

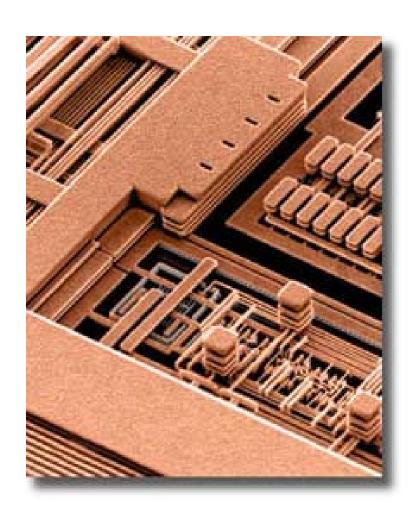


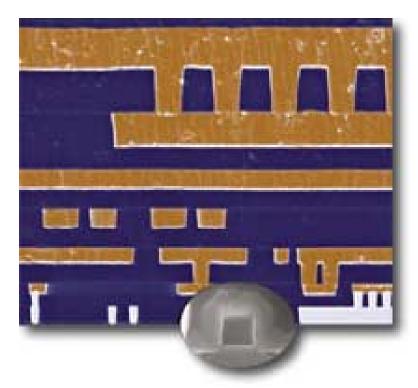
Take the cover off a microprocessor. What do you see?

- A thick web of interconnects, many levels deep.
- High density of very small transistors.

Intel's Pentium IV

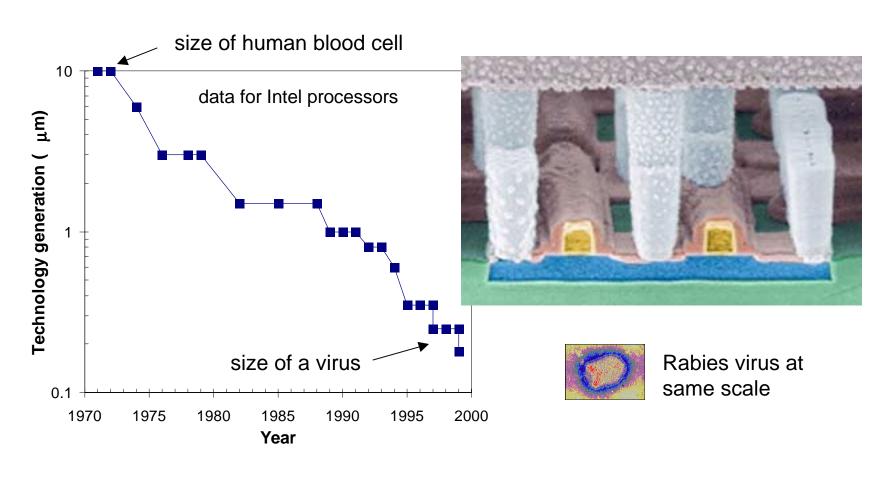
Interconnects





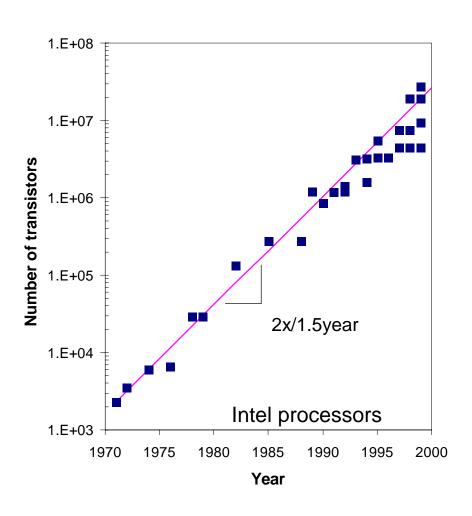
Today, as many as 7 levels of interconnect using Cu.

Transistor size scaling



2-orders of magnitude reduction in transistor size in 30 years.

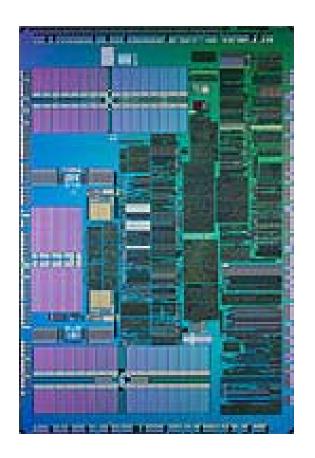
Evolution of transistor density



Moore's Law: doubling of transistor density every 1.5 years

4-orders of magnitude improvement in 30 years.

Benefits of increasing transistor integration

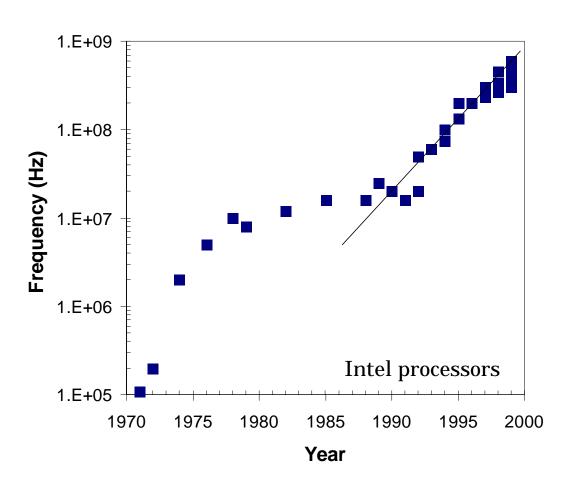


Exponential improvements in:

- system performance
- cost-per-function,
- power-per-function, and
- system reliability.

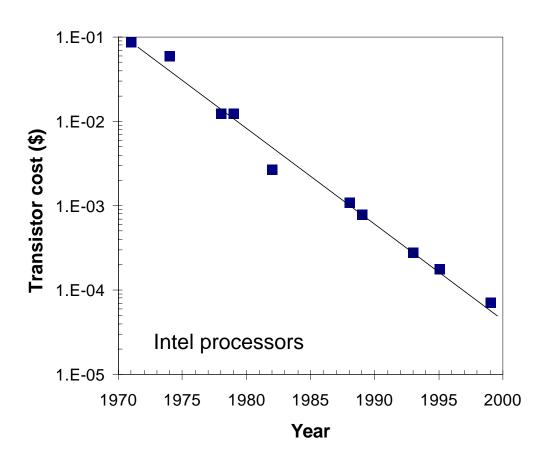
Experimental SOI microprocessor from IBM

Clock speed



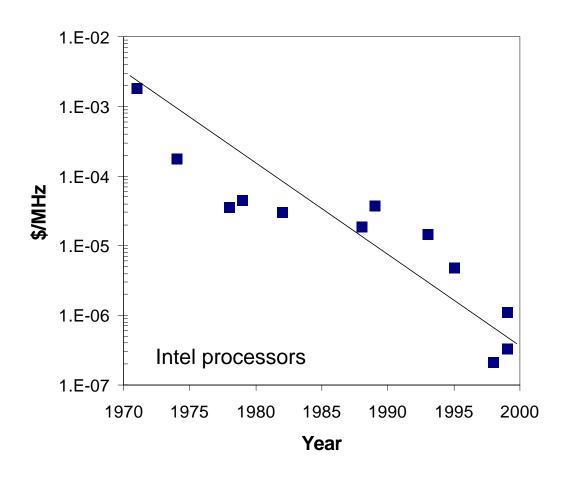
4-orders of magnitude improvement in 30 years.

Transistor cost



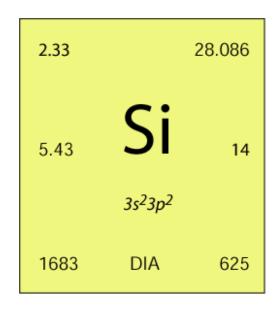
3-order of magnitude reduction in 30 years.

Cost per function



4-order of magnitude reduction in 30 years.

Keys to success of digital microelectronics: I. Silicon



- Cheap and abundant
- Amazing mechanical, chemical and electronic properties
- Probably, the material best known to humankind

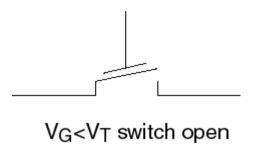
Keys to success of digital microelectronics: II. MOSFET

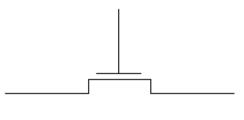
Metal-Oxide-Semiconductor Field-Effect Transistor

source drain
inversion layer gate oxide

Good gain, isolation, and speed

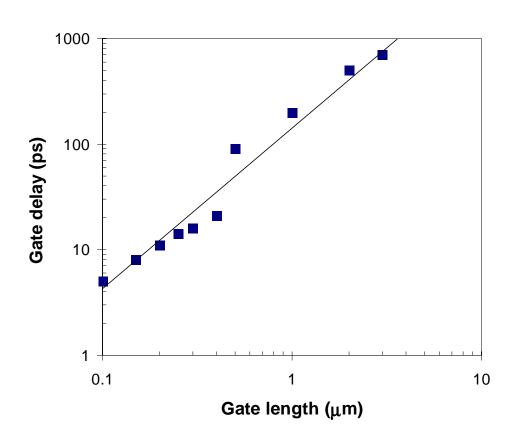
MOSFET = switch





VG>VT switch closed

Keys to success of digital microelectronics: III. MOSFET scaling

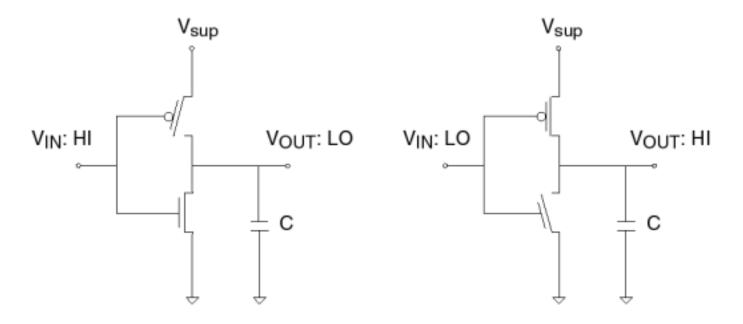


MOSFET performance improves as size is decreased:

- Shorter switching time
- Lower power consumption

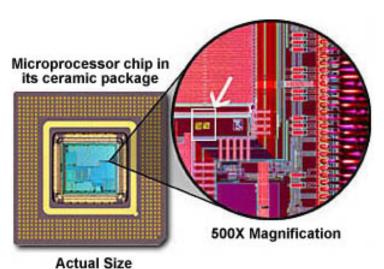
Keys to success of digital microelectronics: IV. CMOS

CMOS: Complementary Metal-Oxide-Semiconductor



- "Complementary" switch activates with V<0.
- Logic without DC power consumption.

Keys to success of digital microelectronics: V. Microfabrication technology



Silicon Graphics MIPS R12000

- Tight integration of dissimilar devices with good isolation
- Fabrication of extremely small structures, precisely and reproducibly
- High-volume manufacturing of complex systems with high yield.

Keys to success of digital microelectronics: VI. Circuit engineering

- Simple device models that:
 - are based on physics
 - allow analog and digital circuit design
 - permit assessment of impact of device variations on circuit performance
- Circuit design techniques that:
 - are tolerant to logic level fluctuations, noise and crosstalk
 - are insensitive to manufacturing variations
 - require little power consumption

Content of 6.012

Deals with microelectronic devices

- Semiconductor physics
- Metal-oxide-semiconductor field-effect transistor (MOSFET)
- Bipolar junction transistor (BJT)
- Deals with microelectronic circuits
 - Digital circuits (mainly CMOS)
 - Analog circuits (BJT and MOS)

"One shouldn't work on semiconductors, that is a filthy mess; who knows if they really exist!"

Wolfgang Pauli, 1931

"To the electron – may it never be of any use to anybody."

favorite toast at annual dinners at Cavendish Laboratory, early 1900's